

SK34B SCHOTTKY RECTIFIER

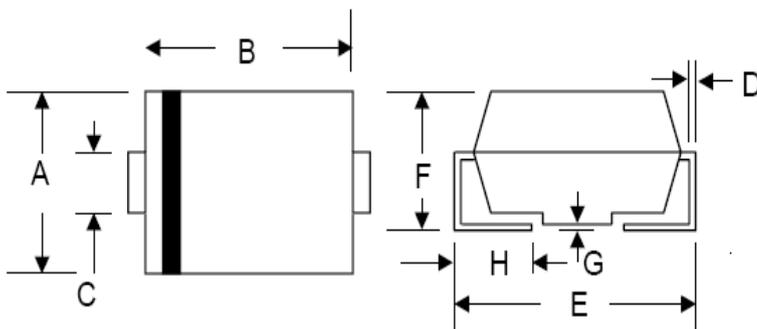
Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Disk drives
- Battery charging

Features:

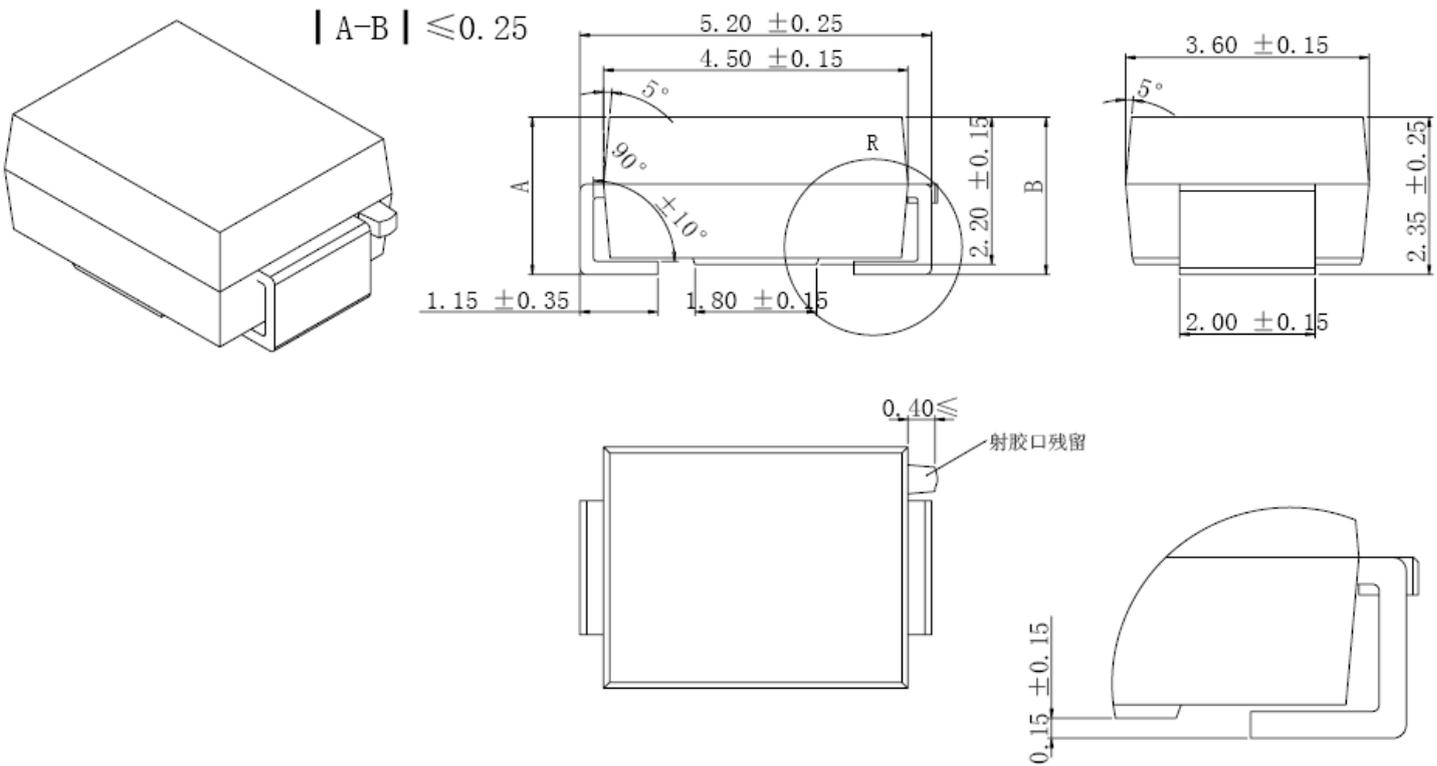
- Small foot print, surface mountable
- Very low forward Voltage Drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Green Products in Compliance the ROHS Directive
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm



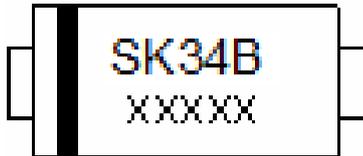
SMB/DO-214AA				
Dim	Min	Max	Min	Max
A	3.30	3.94	0.130	0.155
B	4.06	4.70	0.160	0.185
C	1.91	2.11	0.075	0.083
D	0.152	0.305	0.006	0.012
E	5.08	5.59	0.2	0.220
F	2.13	2.44	0.084	0.096
G	0.051	0.203	0.002	0.008
H	0.76	1.27	0.029	0.05
			in mm	In inch

OPTION 1



OPTION 2(JK)

SMB

Marking Diagram:


Where XXXXX is YYWWL

SK	= Device Type
3	= Forward Current (3A)
4	= Reverse Voltage (40V)
B	= Package type
YY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin
 Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
SK34B	SMB (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	-	40	V
Average Forward Current	$I_{F(AV)}$	@ $T_L = 105^\circ\text{C}$ (Note1)	3.0	A
Peak One Cycle Non-Repetitive Surge Current	I_{FSM}	8.3 ms, half Sine pulse	75	A

Note1: Rectangular wave form, 50% duty cycle, T_L (Lead Temperature) = T_T (Terminal Temperature)



Electrical Characteristics:

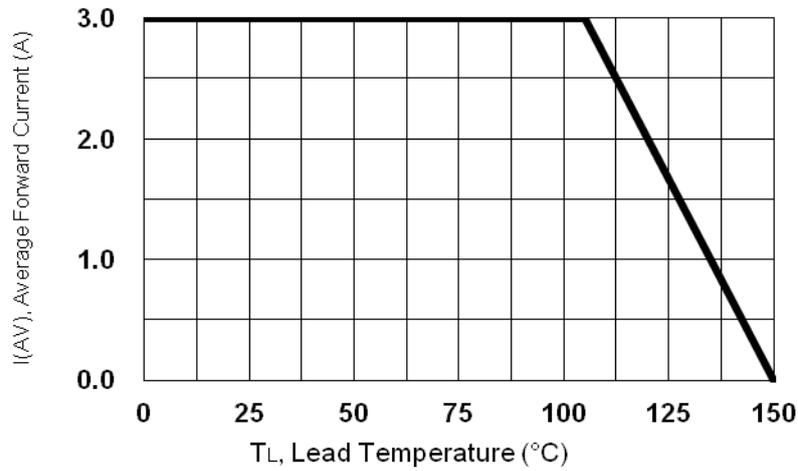
Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 3A, Pulse, T _J = 25°C	0.63	V
	V _{F2}	@ 3A, Pulse, T _J = 125°C	0.57	V
Reverse Current*	I _{R1}	@V _R = rated VR T _J = 25°C	1.0	mA
	I _{R2}	@V _R = rated VR T _J = 125°C	20	mA
Typical Junction Capacitance	C _j	@V _R = 5.0 V, T _c =25°C f _{SIG} = 1MHz	60	pF

* Pulse Width < 300µs, Duty Cycle <2%

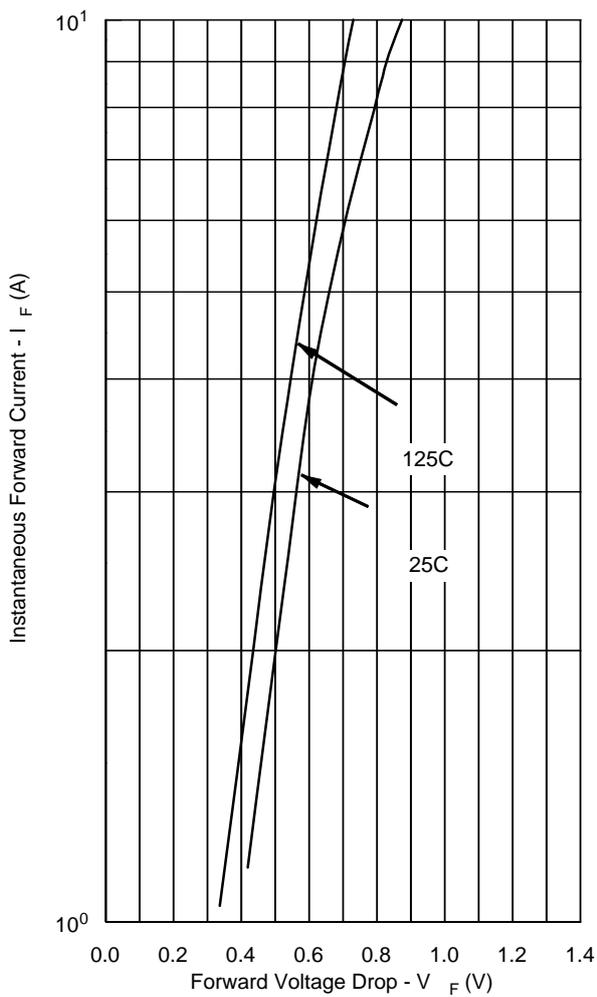
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T _J	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Lead	R _{θJL}	DC operation	25	°C/W
Approximate Weight	wt	-	0.68	g
Case Style	SMB			

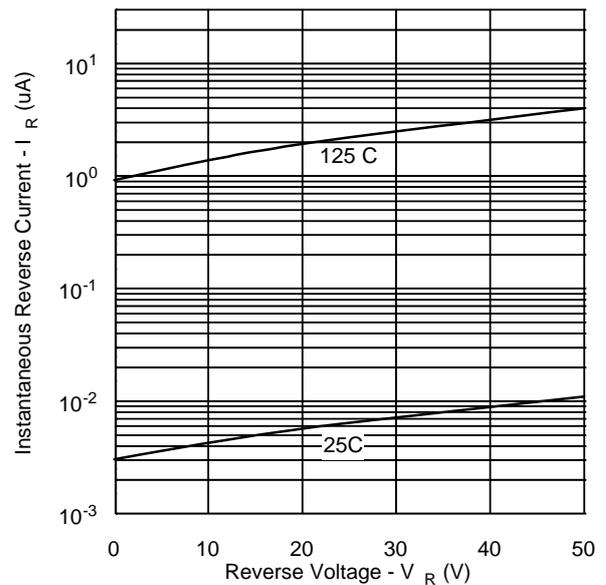
Forward Current Derating Curve



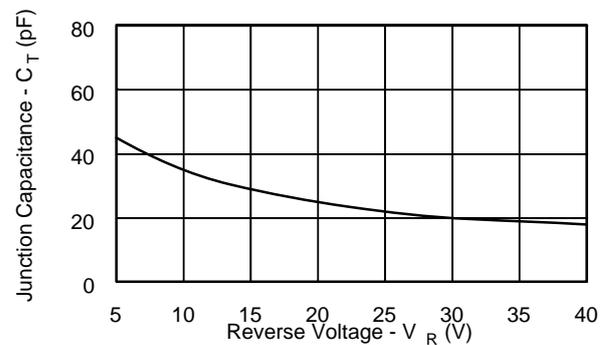
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance





SK34B

Technical Data
Data Sheet N0935, Rev. B

Green Products

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